

## isc N-Channel MOSFET Transistor

## IXTH15N50L2

### • FEATURES

- Static drain-source on-resistance:  
 $R_{DS(on)} \leq 480\text{m}\Omega @ V_{GS}=10\text{V}$
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### • APPLICATION

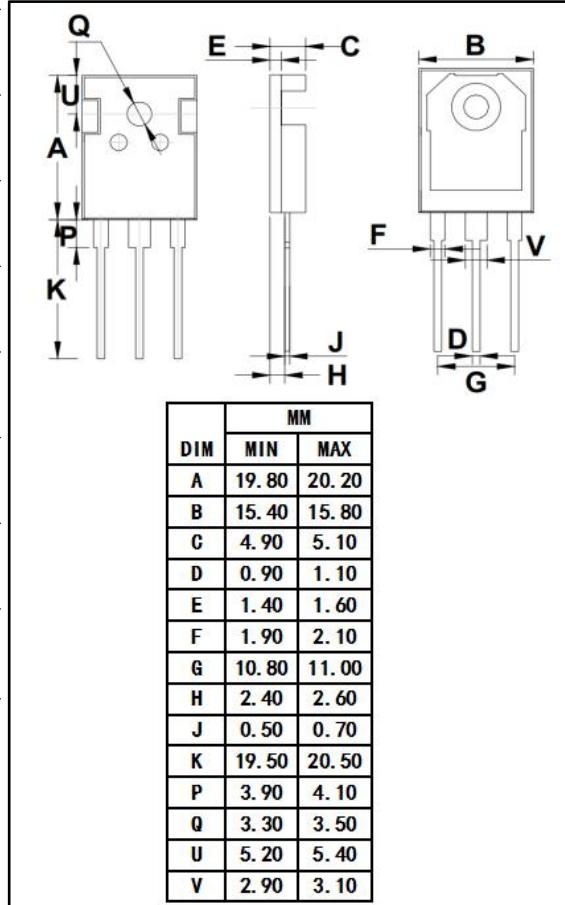
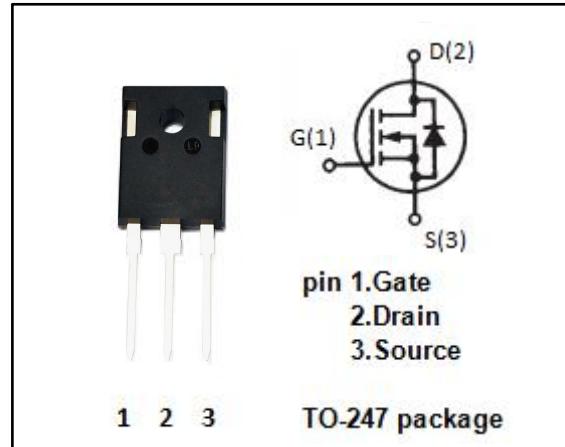
- Current Regulators
- Solid State Circuit Breakers

### • ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	500	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$I_D$	Drain Current-Continuous	15	A
$I_{DM}$	Drain Current-Single Pulsed	35	A
$P_D$	Total Dissipation @ $T_c=25^\circ\text{C}$	300	W
$T_j$	Operating Junction Temperature	-55~150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-55~150	$^\circ\text{C}$

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(j-c)}$	Junction-to-case thermal resistance	0.42	$^\circ\text{C}/\text{W}$



**isc N-Channel MOSFET Transistor****IXTH15N50L2****ELECTRICAL CHARACTERISTICS** $T_c=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
$\text{BV}_{\text{DSS}}$	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}; \text{ID} = 250 \mu\text{A}$	500		V
$\text{V}_{\text{GS(th)}}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}; \text{ID} = 250 \mu\text{A}$	2.5	4.5	V
$\text{R}_{\text{DS(on)}}$	Drain-Source On-Resistance	$\text{V}_{\text{GS}}=10\text{V}; \text{I}_D = 7.5\text{A}$		480	$\text{m}\Omega$
$\text{I}_{\text{GSS}}$	Gate-Source Leakage Current	$\text{V}_{\text{GS}} = \pm 20\text{V}; \text{V}_{\text{DS}}=0\text{V}$		$\pm 100$	nA
$\text{I}_{\text{DSS}}$	Drain-Source Leakage Current	$\text{V}_{\text{DS}} = \text{V}_{\text{DSS}}; \text{V}_{\text{GS}} = 0\text{V}$		25	$\mu\text{A}$
		$\text{V}_{\text{DS}} = \text{V}_{\text{DSS}}; \text{V}_{\text{GS}} = 0\text{V}; \text{T}_J = 125^\circ\text{C}$		200	
$\text{V}_{\text{SD}}$	Diode forward voltage	$\text{I}_F = 15\text{A}; \text{V}_{\text{GS}} = 0\text{V}$		1.5	V

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